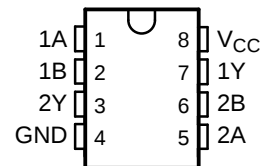


## FEATURES

- **Controlled Baseline**
  - One Assembly/Test Site, One Fabrication Site
- **Extended Temperature Performance of –55°C to 115°C**
- **Enhanced Diminishing Manufacturing Sources (DMS) Support**
- **Enhanced Product-Change Notification**
- **Qualification Pedigree <sup>(1)</sup>**
- **Supports 5-V  $V_{CC}$  Operation**
- **Inputs Accept Voltages to 5.5 V**
- **Max  $t_{pd}$  of 5.3 ns at 3.3 V**
- **Low Power Consumption, 10- $\mu$ A Max  $I_{CC}$**
- (1) Component qualification in accordance with JEDEC and industry standards to ensure reliable operation over an extended temperature range. This includes, but is not limited to, Highly Accelerated Stress Test (HAST) or biased 85/85, temperature cycle, autoclave or unbiased HAST, electromigration, bond intermetallic life, and mold compound life. Such qualification testing should not be viewed as justifying use of this component beyond specified performance and environmental limits.
- **$\pm 24$ -mA Output Drive at 3.3 V**
- **Typical  $V_{OLP}$  (Output Ground Bounce)  $< 0.8$  V at  $V_{CC} = 3.3$  V,  $T_A = 25^\circ\text{C}$**
- **Typical  $V_{OHV}$  (Output  $V_{OH}$  Undershoot)  $> 2$  V at  $V_{CC} = 3.3$  V,  $T_A = 25^\circ\text{C}$**
- **$I_{off}$  Supports Partial-Power-Down Mode Operation**
- **Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II**
- **ESD Protection Exceeds JESD 22**
  - 2000-V Human-Body Model (A114-A)
  - 1000-V Charged-Device Model (C101)

**DCT PACKAGE  
(TOP VIEW)**



## DESCRIPTION/ORDERING INFORMATION

This dual 2-input positive-NAND gate is designed for 1.65-V to 5.5-V  $V_{CC}$  operation.

The SN74LVC2G00W-EP performs the Boolean function  $Y = \overline{A \bullet B}$  or  $Y = \overline{A} + \overline{B}$  in positive logic.

This device is fully specified for partial-power-down applications using  $I_{off}$ . The  $I_{off}$  circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

### ORDERING INFORMATION

| $T_A$          | PACKAGE <sup>(1)</sup> |              | ORDERABLE PART NUMBER | TOP-SIDE MARKING <sup>(2)</sup> |
|----------------|------------------------|--------------|-----------------------|---------------------------------|
| –55°C to 115°C | SSOP – DCT             | Reel of 3000 | SN74LVC2G00WDCTREP    | C00_ _ _                        |

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at [www.ti.com/sc/package](http://www.ti.com/sc/package).

(2) DCT: The actual top-side marking has three additional characters that designate the year, month, and assembly/test site.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

# SN74LVC2G00W-EP

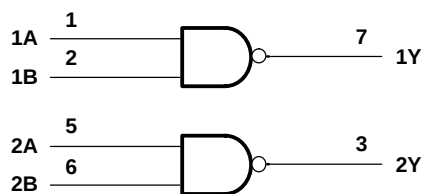
## DUAL 2-INPUT POSITIVE-NAND GATE

SCES645–SEPTEMBER 2005

**FUNCTION TABLE  
(EACH GATE)**

| INPUTS |   | OUTPUT<br>Y |
|--------|---|-------------|
| A      | B |             |
| H      | H | L           |
| L      | X | H           |
| X      | L | H           |

**LOGIC DIAGRAM (POSITIVE LOGIC)**



### Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

|               |                                                                                             | MIN       | MAX            | UNIT |
|---------------|---------------------------------------------------------------------------------------------|-----------|----------------|------|
| $V_{CC}$      | Supply voltage range                                                                        | −0.5      | 6.5            | V    |
| $V_I$         | Input voltage range <sup>(2)</sup>                                                          | −0.5      | 6.5            | V    |
| $V_O$         | Voltage range applied to any output in the high-impedance or power-off state <sup>(2)</sup> | −0.5      | 6.5            | V    |
| $V_O$         | Voltage range applied to any output in the high or low state <sup>(2)(3)</sup>              | −0.5      | $V_{CC} + 0.5$ | V    |
| $I_{IK}$      | Input clamp current                                                                         | $V_I < 0$ | −50            | mA   |
| $I_{OK}$      | Output clamp current                                                                        | $V_O < 0$ | −50            | mA   |
| $I_O$         | Continuous output current                                                                   |           | ±50            | mA   |
|               | Continuous current through $V_{CC}$ or GND                                                  |           | ±100           | mA   |
| $\theta_{JA}$ | Package thermal impedance <sup>(4)</sup>                                                    |           | 220            | °C/W |
| $T_{stg}$     | Storage temperature range                                                                   | −65       | 150            | °C   |

- (1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) The input negative-voltage and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- (3) The value of  $V_{CC}$  is provided in the recommended operating conditions table.
- (4) The package thermal impedance is calculated in accordance with JESD 51-7.

### Recommended Operating Conditions<sup>(1)</sup>

|                 |                                    | MIN                                             | MAX                    | UNIT |      |
|-----------------|------------------------------------|-------------------------------------------------|------------------------|------|------|
| V <sub>CC</sub> | Supply voltage                     | Operating                                       | 1.65                   | 5.5  | V    |
|                 |                                    | Data retention only                             | 1.5                    |      |      |
| V <sub>IH</sub> | High-level input voltage           | V <sub>CC</sub> = 1.65 V to 1.95 V              | 0.65 × V <sub>CC</sub> |      | V    |
|                 |                                    | V <sub>CC</sub> = 2.3 V to 2.7 V                | 1.7                    |      |      |
|                 |                                    | V <sub>CC</sub> = 3 V to 3.6 V                  | 2                      |      |      |
|                 |                                    | V <sub>CC</sub> = 4.5 V to 5.5 V                | 0.7 × V <sub>CC</sub>  |      |      |
| V <sub>IL</sub> | Low-level input voltage            | V <sub>CC</sub> = 1.65 V to 1.95 V              | 0.35 × V <sub>CC</sub> |      | V    |
|                 |                                    | V <sub>CC</sub> = 2.3 V to 2.7 V                | 0.7                    |      |      |
|                 |                                    | V <sub>CC</sub> = 3 V to 3.6 V                  | 0.8                    |      |      |
|                 |                                    | V <sub>CC</sub> = 4.5 V to 5.5 V                | 0.3 × V <sub>CC</sub>  |      |      |
| V <sub>I</sub>  | Input voltage                      | 0                                               | 5.5                    |      | V    |
| V <sub>O</sub>  | Output voltage                     | 0                                               | V <sub>CC</sub>        |      | V    |
| I <sub>OH</sub> | High-level output current          | V <sub>CC</sub> = 1.65 V                        | –4                     |      | mA   |
|                 |                                    | V <sub>CC</sub> = 2.3 V                         | –8                     |      |      |
|                 |                                    | V <sub>CC</sub> = 3 V                           | –16                    |      |      |
|                 |                                    |                                                 | –24                    |      |      |
| I <sub>OL</sub> | Low-level output current           | V <sub>CC</sub> = 4.5 V                         | –32                    |      | mA   |
|                 |                                    | V <sub>CC</sub> = 1.65 V                        | 4                      |      |      |
|                 |                                    | V <sub>CC</sub> = 2.3 V                         | 8                      |      |      |
|                 |                                    | V <sub>CC</sub> = 3 V                           | 16                     |      |      |
| 24              |                                    |                                                 |                        |      |      |
| Δt/Δv           | Input transition rise or fall rate | V <sub>CC</sub> = 4.5 V                         | 32                     |      | ns/V |
|                 |                                    | V <sub>CC</sub> = 1.8 V ± 0.15 V, 2.5 V ± 0.2 V | 20                     |      |      |
|                 |                                    | V <sub>CC</sub> = 3.3 V ± 0.3 V                 | 10                     |      |      |
|                 |                                    | V <sub>CC</sub> = 5 V ± 0.5 V                   | 5                      |      |      |
| T <sub>A</sub>  | Operating free-air temperature     | –55                                             | 115                    |      | °C   |

(1) All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

# SN74LVC2G00W-EP

## DUAL 2-INPUT POSITIVE-NAND GATE

SCES645–SEPTEMBER 2005

### Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER        |               | TEST CONDITIONS                                                              | V <sub>CC</sub> | MIN                   | TYP <sup>(1)</sup> | MAX  | UNIT |
|------------------|---------------|------------------------------------------------------------------------------|-----------------|-----------------------|--------------------|------|------|
| V <sub>OH</sub>  |               | I <sub>OH</sub> = –100 µA                                                    | 1.65 V to 5.5 V | V <sub>CC</sub> – 0.1 |                    |      | V    |
|                  |               | I <sub>OH</sub> = –4 mA                                                      | 1.65 V          | 1.2                   |                    |      |      |
|                  |               | I <sub>OH</sub> = –8 mA                                                      | 2.3 V           | 1.9                   |                    |      |      |
|                  |               | I <sub>OH</sub> = –16 mA                                                     | 3 V             | 2.4                   |                    |      |      |
|                  |               | I <sub>OH</sub> = –24 mA                                                     |                 | 2.3                   |                    |      |      |
|                  |               | I <sub>OH</sub> = –32 mA                                                     | 4.5 V           | 3.8                   |                    |      |      |
| V <sub>OL</sub>  |               | I <sub>OL</sub> = 100 µA                                                     | 1.65 V to 5.5 V |                       |                    | 0.1  | V    |
|                  |               | I <sub>OL</sub> = 4 mA                                                       | 1.65 V          |                       |                    | 0.45 |      |
|                  |               | I <sub>OL</sub> = 8 mA                                                       | 2.3 V           |                       |                    | 0.3  |      |
|                  |               | I <sub>OL</sub> = 16 mA                                                      | 3 V             |                       |                    | 0.4  |      |
|                  |               | I <sub>OL</sub> = 24 mA                                                      |                 |                       |                    | 0.55 |      |
|                  |               | I <sub>OL</sub> = 32 mA                                                      | 4.5 V           |                       |                    | 0.57 |      |
| I <sub>I</sub>   | A or B inputs | V <sub>I</sub> = 5.5 V or GND                                                | 0 to 5.5 V      |                       |                    | ±5   | µA   |
| I <sub>off</sub> |               | V <sub>I</sub> or V <sub>O</sub> = 5.5 V                                     | 0               |                       |                    | ±10  | µA   |
| I <sub>CC</sub>  |               | V <sub>I</sub> = 5.5 V or GND, I <sub>O</sub> = 0                            | 1.65 V to 5.5 V |                       |                    | 10   | µA   |
| ΔI <sub>CC</sub> |               | One input at V <sub>CC</sub> – 0.6 V, Other inputs at V <sub>CC</sub> or GND | 3 V to 5.5 V    |                       |                    | 500  | µA   |
| C <sub>i</sub>   |               | V <sub>I</sub> = V <sub>CC</sub> or GND                                      | 3.3 V           |                       |                    | 5    | pF   |

(1) All typical values are at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C.

### Switching Characteristics

over recommended operating free-air temperature range (unless otherwise noted) (see [Figure 1](#))

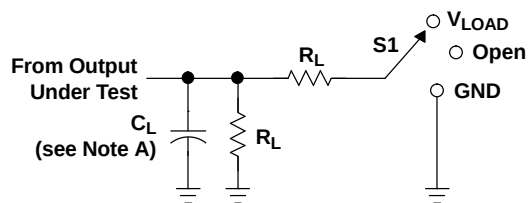
| PARAMETER       | FROM<br>(INPUT) | TO<br>(OUTPUT) | V <sub>CC</sub> = 1.8 V<br>± 0.15 V |     | V <sub>CC</sub> = 2.5 V<br>± 0.2 V |     | V <sub>CC</sub> = 3.3 V<br>± 0.3 V |     | V <sub>CC</sub> = 5 V<br>± 0.5 V |     | UNIT |
|-----------------|-----------------|----------------|-------------------------------------|-----|------------------------------------|-----|------------------------------------|-----|----------------------------------|-----|------|
|                 |                 |                | MIN                                 | MAX | MIN                                | MAX | MIN                                | MAX | MIN                              | MAX |      |
| t <sub>pd</sub> | A or B          | Y              | 3.7                                 | 8.9 | 1.6                                | 5.8 | 1.1                                | 5.3 | 1                                | 4.3 | ns   |

### Operating Characteristics

T<sub>A</sub> = 25°C

| PARAMETER                                     | TEST CONDITIONS | V <sub>CC</sub> = 1.8 V | V <sub>CC</sub> = 2.5 V | V <sub>CC</sub> = 3.3 V | V <sub>CC</sub> = 5 V | UNIT |
|-----------------------------------------------|-----------------|-------------------------|-------------------------|-------------------------|-----------------------|------|
|                                               |                 | TYP                     | TYP                     | TYP                     | TYP                   |      |
| C <sub>pd</sub> Power dissipation capacitance | f = 10 MHz      | 19                      | 19                      | 20                      | 22                    | pF   |

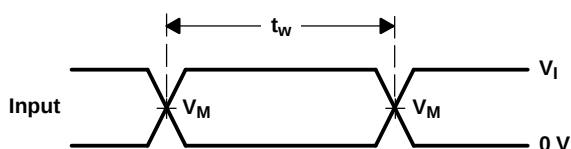
## PARAMETER MEASUREMENT INFORMATION



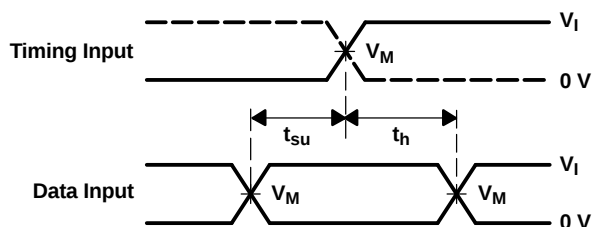
LOAD CIRCUIT

| TEST              | S1         |
|-------------------|------------|
| $t_{PLH}/t_{PHL}$ | Open       |
| $t_{PLZ}/t_{PZL}$ | $V_{LOAD}$ |
| $t_{PHZ}/t_{PZH}$ | GND        |

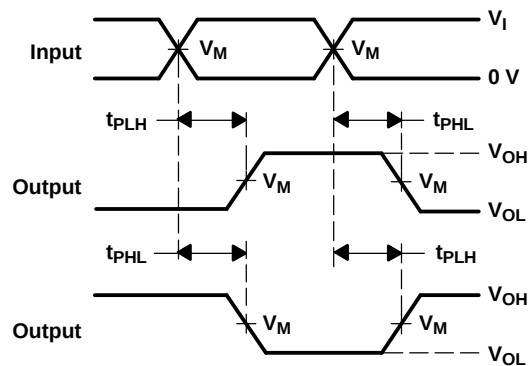
| $V_{CC}$                         | INPUTS   |                      | $V_M$      | $V_{LOAD}$        | $C_L$ | $R_L$        | $V_{\Delta}$ |
|----------------------------------|----------|----------------------|------------|-------------------|-------|--------------|--------------|
|                                  | $V_I$    | $t_r/t_f$            |            |                   |       |              |              |
| $1.8\text{ V} \pm 0.15\text{ V}$ | $V_{CC}$ | $\leq 2\text{ ns}$   | $V_{CC}/2$ | $2 \times V_{CC}$ | 30 pF | 1 k $\Omega$ | 0.15 V       |
| $2.5\text{ V} \pm 0.2\text{ V}$  | $V_{CC}$ | $\leq 2\text{ ns}$   | $V_{CC}/2$ | $2 \times V_{CC}$ | 30 pF | 500 $\Omega$ | 0.15 V       |
| $3.3\text{ V} \pm 0.3\text{ V}$  | 3 V      | $\leq 2.5\text{ ns}$ | 1.5 V      | 6 V               | 50 pF | 500 $\Omega$ | 0.3 V        |
| $5\text{ V} \pm 0.5\text{ V}$    | $V_{CC}$ | $\leq 2.5\text{ ns}$ | $V_{CC}/2$ | $2 \times V_{CC}$ | 50 pF | 500 $\Omega$ | 0.3 V        |



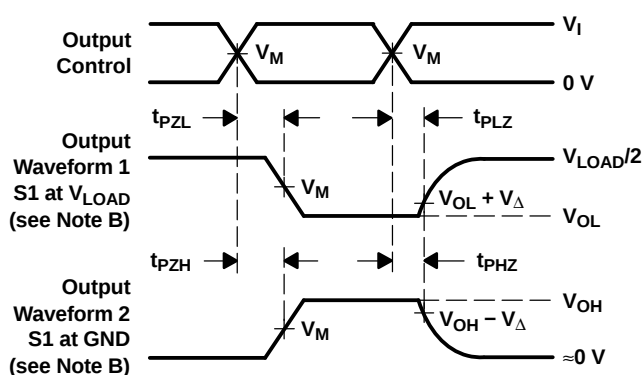
VOLTAGE WAVEFORMS  
PULSE DURATION



VOLTAGE WAVEFORMS  
SETUP AND HOLD TIMES



VOLTAGE WAVEFORMS  
PROPAGATION DELAY TIMES  
INVERTING AND NONINVERTING OUTPUTS



VOLTAGE WAVEFORMS  
ENABLE AND DISABLE TIMES  
LOW- AND HIGH-LEVEL ENABLING

- NOTES:
- $C_L$  includes probe and jig capacitance.
  - Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
  - All input pulses are supplied by generators having the following characteristics:  $PRR \leq 10\text{ MHz}$ ,  $Z_O = 50\ \Omega$ .
  - The outputs are measured one at a time, with one transition per measurement.
  - $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
  - $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
  - $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .
  - All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms

## PACKAGING INFORMATION

| Orderable part number              | Status<br>(1) | Material type<br>(2) | Package   Pins | Package qty   Carrier | RoHS<br>(3) | Lead finish/<br>Ball material<br>(4) | MSL rating/<br>Peak reflow<br>(5) | Op temp (°C) | Part marking<br>(6) |
|------------------------------------|---------------|----------------------|----------------|-----------------------|-------------|--------------------------------------|-----------------------------------|--------------|---------------------|
| <a href="#">SN74LVC2G00WDCTREP</a> | Active        | Production           | SSOP (DCT)   8 | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -55 to 115   | COO<br>Z            |
| <a href="#">V62/05623-01XE</a>     | Active        | Production           | SSOP (DCT)   8 | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -55 to 115   | COO<br>Z            |

<sup>(1)</sup> **Status:** For more details on status, see our [product life cycle](#).

<sup>(2)</sup> **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

<sup>(4)</sup> **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "-" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

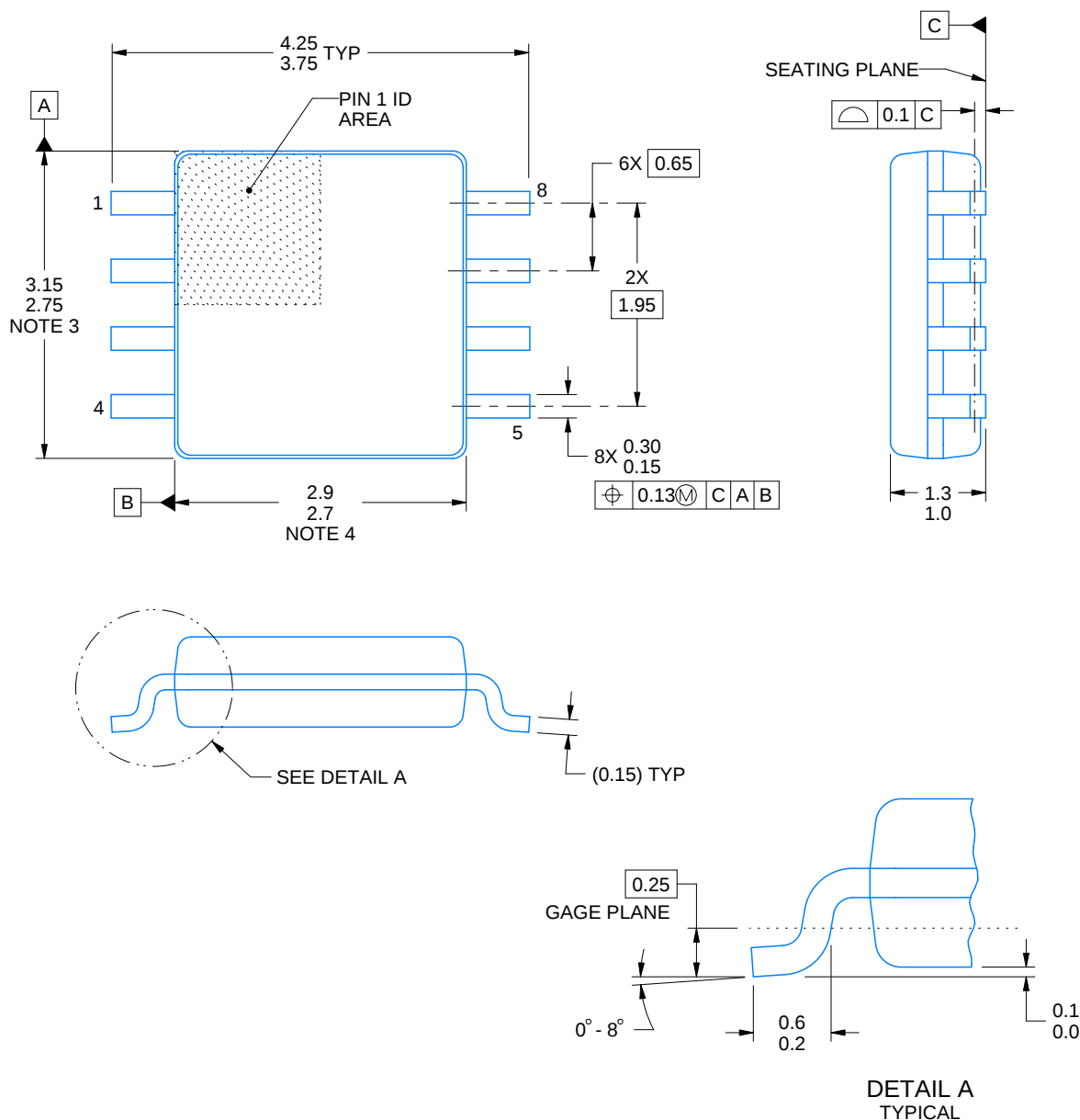
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**PACKAGE OUTLINE**  
**SSOP - 1.3 mm max height**

SMALL OUTLINE PACKAGE



4220784/C 06/2021

NOTES:

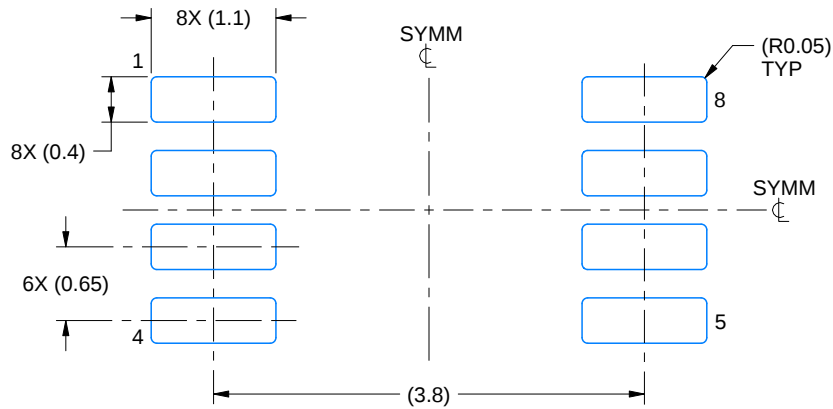
1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.

# EXAMPLE BOARD LAYOUT

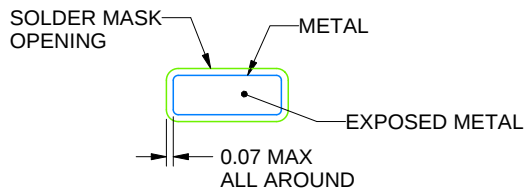
DCT0008A

SSOP - 1.3 mm max height

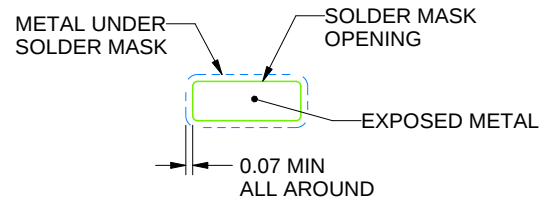
SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE:15X



NON SOLDER MASK  
DEFINED



SOLDER MASK  
DEFINED

SOLDER MASK DETAILS

4220784/C 06/2021

NOTES: (continued)

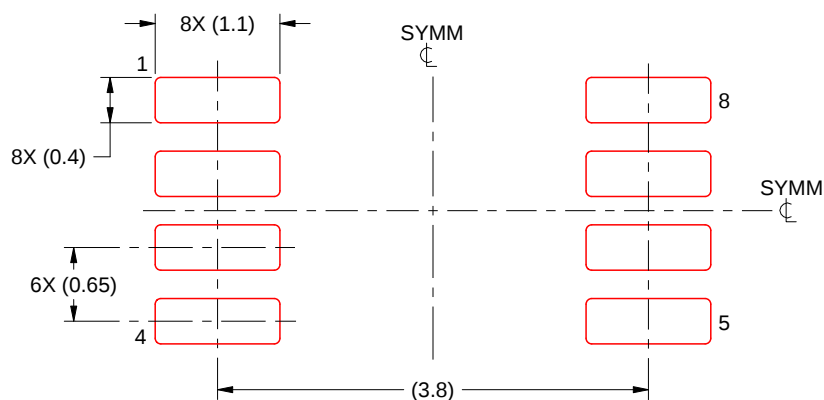
5. Publication IPC-7351 may have alternate designs.
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

## EXAMPLE STENCIL DESIGN

DCT0008A

SSOP - 1.3 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE:15X

4220784/C 06/2021

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.

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Last updated 10/2025